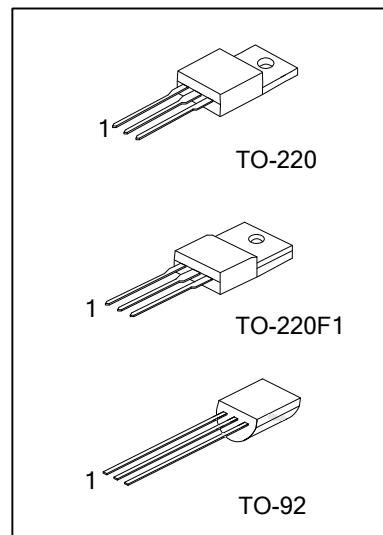


1.3A, 500V N-CHANNEL POWER MOSFET

■ DESCRIPTION

The UTC **1N50** is a N-channel mode power MOSFET using UTC's advanced technology to provide customers with planar stripe and DMOS technology. This technology allows a minimum on-state resistance and superior switching performance. It also can withstand high energy pulse in the avalanche and commutation mode.

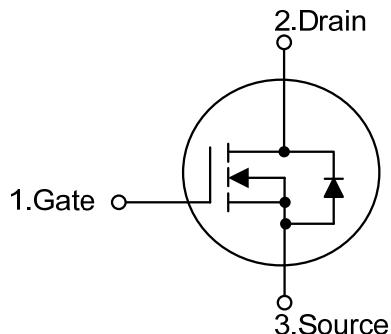
The UTC **1N50** is generally applied in high efficiency switch mode power supplies, active power factor correction and electronic lamp ballasts based on half bridge topology.



■ FEATURES

- * $R_{DS(ON)}=6.0\Omega$ @ $V_{GS}=10V$
- * High Switching Speed
- * 100% Avalanche Tested

■ SYMBOL



■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
1N50L-TA3-T	1N50G-TA3-T	TO-220	G	D	S	Tube
1N50L-TF1-T	1N50G-TF1-T	TO-220F1	G	D	S	Tube
1N50L-92-B	1N50G-T92-B	TO-92	G	D	S	Tape Box
1N50L-92-K	1N50G-T92-K	TO-92	G	D	S	Bulk

Note: Pin Assignment: G: Gate D: Drain S: Source

1N50L-TA3-T	(1)Packing Type	(1) T: Tube, B: Tape Box, K: Bulk
	(2)Package Type	(2) TA3: TO-220, TF1: TO-220F1, T92: TO-92
	(3)Green Package	(3) L: Lead Free, G: Halogen Free and Lead Free

■ MARKING

TO-220 / TO-220F1	TO-92
<p>Diagram illustrating the marking layout for TO-220 and TO-220F1 packages. The markings are as follows:</p> <ul style="list-style-type: none">Top Row: UTC (top left), 1N50 (center), and a small square symbol (top right).Bottom Row: A series of five small squares representing the Data Code.Left Side: A vertical line labeled "1" at the bottom, with an arrow pointing to the left indicating the Lot Code.Right Side: Arrows pointing to the right indicate the meanings of the symbols:<ul style="list-style-type: none">L: Lead FreeG: Halogen FreeData Code	<p>Diagram illustrating the marking layout for TO-92 packages. The markings are as follows:</p> <ul style="list-style-type: none">Top Row: UTC (top left), 1N50 (center), and a small square symbol (top right).Bottom Row: A series of three small squares representing the Data Code.Right Side: Arrows pointing to the right indicate the meanings of the symbols:<ul style="list-style-type: none">L: Lead FreeG: Halogen FreeData Code

■ ABSOLUTE MAXIMUM RATINGS ($T_c=25^\circ\text{C}$, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	500	V
Gate-Source Voltage		V_{GSS}	± 30	V
Drain Current	Continuous ($T_c=25^\circ\text{C}$)	I_D	1.3 (Note 2)	A
	Pulsed (Note 3)	I_{DM}	5 (Note 2)	A
Avalanche Current (Note 3)		I_{AR}	1.3	A
Avalanche Energy	Single Pulsed (Note 4)	E_{AS}	113	mJ
	Repetitive (Note 5)	E_{AR}	2.6	mJ
Power Dissipation	TO-220	P_D	40	W
	TO-220F1		20	W
	TO-92		1.56	W
Derate above 25°C	TO-220		0.32	$^\circ\text{C}/\text{W}$
	TO-220F1		0.16	$^\circ\text{C}/\text{W}$
	TO-92		0.0125	$^\circ\text{C}/\text{W}$
Junction Temperature		T_J	+150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-55 ~ +150	$^\circ\text{C}$

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Drain current limited by maximum junction temperature

3. Repetitive Rating: Pulse width limited by maximum junction temperature

4. $L = 120\text{mH}$, $I_{AS} = 1.3\text{A}$, $V_{DD} = 50\text{V}$, $R_G = 27\Omega$, Starting $T_J = 25^\circ\text{C}$

5. $I_{SD} \leq 1.5\text{A}$, $dI/dt \leq 200\text{A}/\mu\text{s}$, $V_{DD} \leq BV_{DSS}$, Starting $T_J = 25^\circ\text{C}$

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	TO-220/TO-220F1	θ_{JA}	62.5	$^\circ\text{C}/\text{W}$
	TO-92		180	$^\circ\text{C}/\text{W}$
Junction to Case	TO-220	θ_{JC}	3.13	$^\circ\text{C}/\text{W}$
	TO-220F1		6.24	$^\circ\text{C}/\text{W}$
	TO-92		80	$^\circ\text{C}/\text{W}$

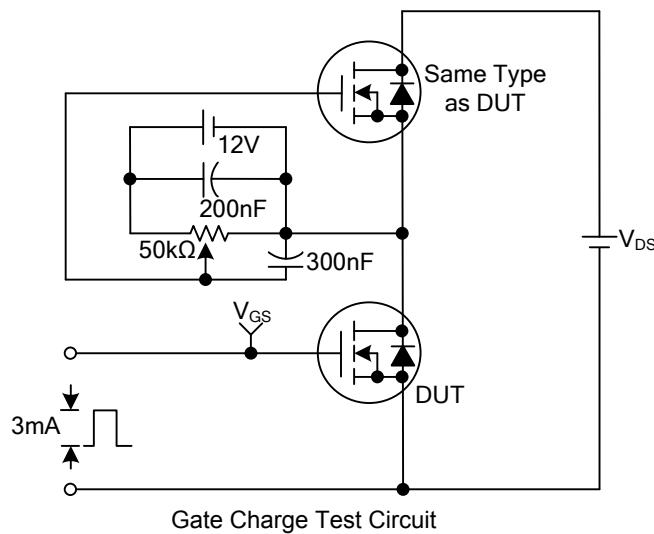
■ ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
OFF CHARACTERISTICS						
Drain-Source Breakdown Voltage	BV_{DSS}	$I_D=250\mu\text{A}, V_{GS}=0\text{V}$	500			V
Drain-Source Leakage Current	I_{DSS}	$V_{DS}=500\text{V}, V_{GS}=0\text{V}$		1		μA
Gate- Source Leakage Current	Forward	$V_{GS}=+30\text{V}, V_{DS}=0\text{V}$			+100	nA
	Reverse	$V_{GS}=-30\text{V}, V_{DS}=0\text{V}$			-100	nA
ON CHARACTERISTICS						
Gate Threshold Voltage	$V_{GS(\text{TH})}$	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	2.0		4.0	V
Static Drain-Source On-State Resistance	$R_{DS(\text{ON})}$	$V_{GS}=10\text{V}, I_D=0.65\text{A}$		4.3	6.0	Ω
DYNAMIC PARAMETERS						
Input Capacitance	C_{ISS}	$V_{GS}=0\text{V}, V_{DS}=25\text{V}, f=1.0\text{MHz}$		220	290	pF
Output Capacitance	C_{OSS}			30	35	pF
Reverse Transfer Capacitance	C_{RSS}			11	13	pF
SWITCHING PARAMETERS						
Turn-ON Delay Time	$t_{D(\text{ON})}$	$V_{DD}=30\text{V}, I_D=0.5\text{A}, R_G=25\Omega$ (Note 1, 2)		44	50	ns
Rise Time	t_R			31	35	ns
Turn-OFF Delay Time	$t_{D(\text{OFF})}$			58	90	ns
Fall-Time	t_F			22	40	ns
Total Gate Charge	Q_G	$V_{GS}=10\text{V}, V_{DS}=50\text{V}, I_D=1.3\text{A}$ (Note 1, 2)		11	16	nC
Gate to Source Charge	Q_{GS}			3.64		nC
Gate to Drain Charge	Q_{GD}			2		nC
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS						
Maximum Body-Diode Continuous Current	I_S				1.3	A
Maximum Body-Diode Pulsed Current	I_{SM}				5	A
Drain-Source Diode Forward Voltage	V_{SD}	$I_S=1.3\text{A}, V_{GS}=0\text{V}$			1.15	V

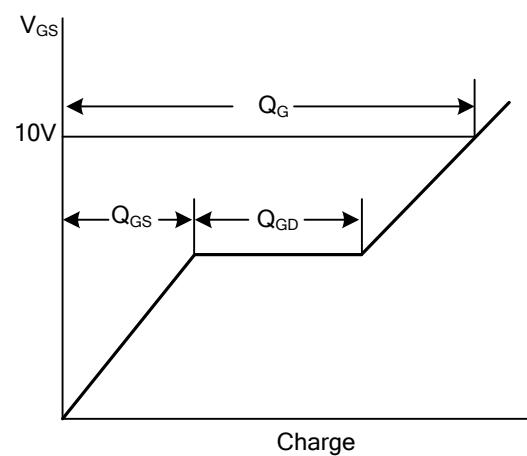
Notes: 1. Pulse Test: Pulse width $\leq 300\mu\text{s}$, Duty cycle $\leq 2\%$

2. Essentially independent of operating temperature

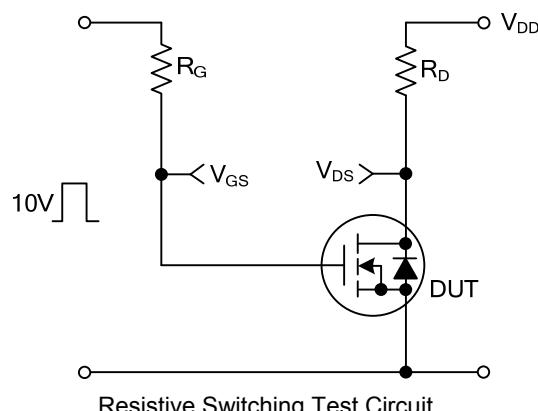
■ TEST CIRCUITS AND WAVEFORMS



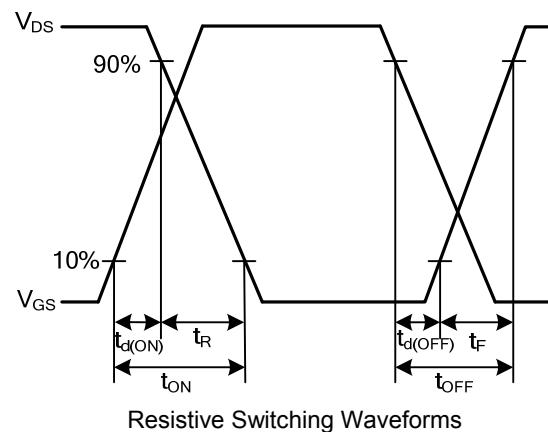
Gate Charge Test Circuit



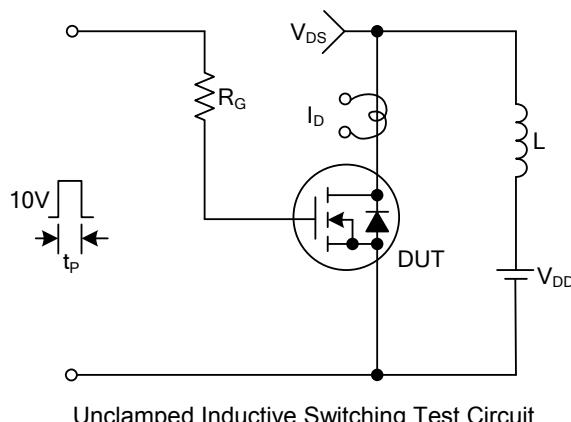
Gate Charge Waveforms



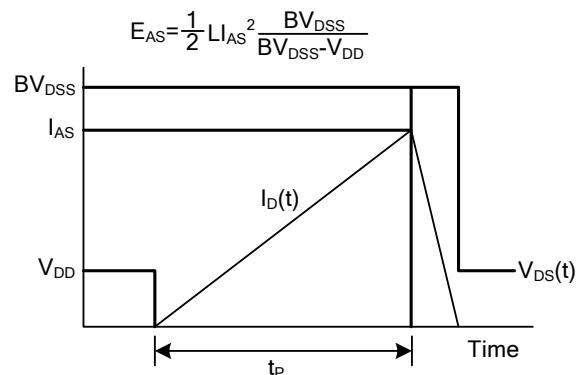
Resistive Switching Test Circuit



Resistive Switching Waveforms

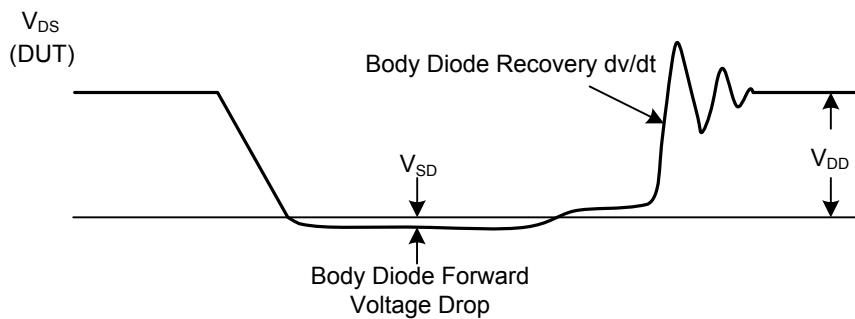
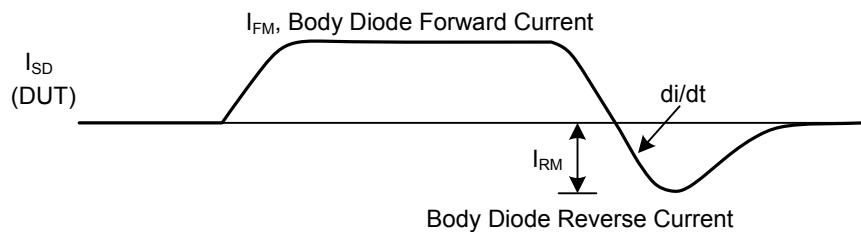
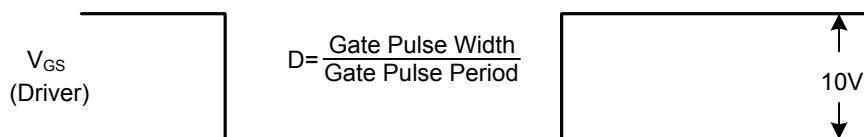
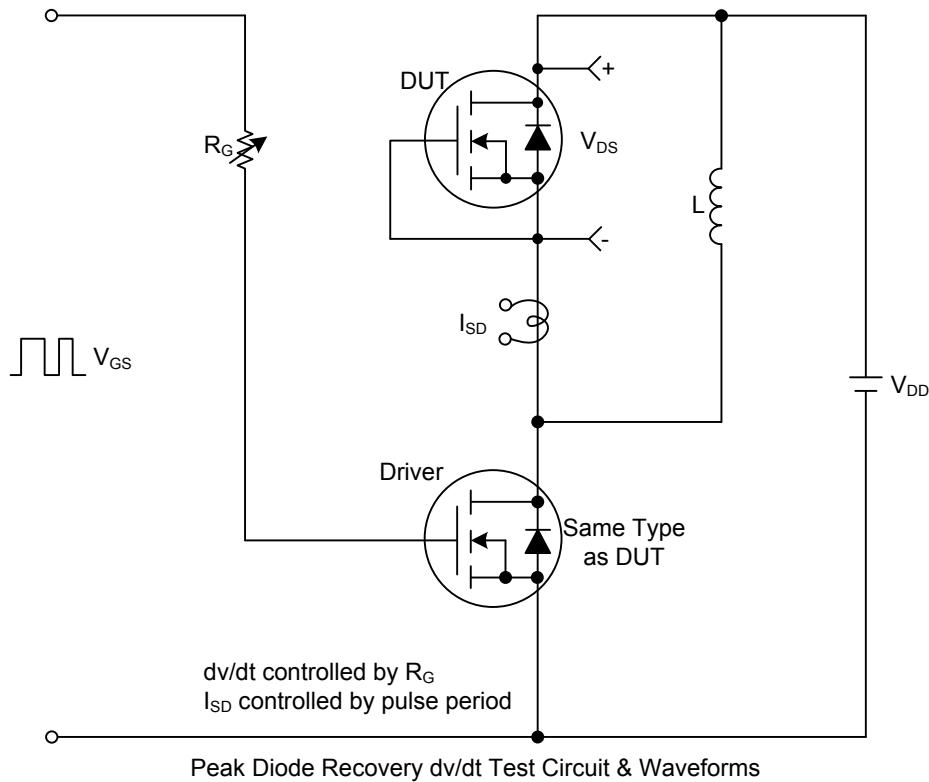


Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms

■ TEST CIRCUITS AND WAVEFORMS(Cont.)



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